

FORM PTO-1449 (SUBSTITUTE) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))	Attorney Docket No.: GR 95 P 1411 Serial No. <u>02 020872</u> Applicant GUNTHER PLASA Filing Date FEBRUARY 9, 1998 Group Art Unit
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EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
<i>WZ</i>	A	5,109,258	04/92	Redwine			
<i>WZ</i>	B	4,400,867	08/83	Fraser			
	C						
	D						
	E						
	F						
	G						
	H						
	I						

FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES	NO
<i>WZ</i>	J	2739662	03/79	Germany				X
<i>WZ</i>	K	2520047	12/75	Germany				X
<i>WZ</i>	L	0294699A2	12/88	Europe			X	
<i>WZ</i>	M	57-42169	03/82	Japan			X	
	N							

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

<i>WZ</i>	IEEE Transactions on Electron Devices, October 1984, Volume ED-31, Number 10
<i>WZ</i>	Japanese Patent Abstract No. 61-248532 (Mitsui), dated November 5, 1986

EXAMINER <i>WZ</i>	DATE CONSIDERED <i>9/27/99</i>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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<i>WZC</i>		IEEE Transactions on Electron Devices, January 1981, Volume ED-28, Number 1
<i>WZC</i>		"Formation of High Quality Storage Capacitor Dielectrics by in-situ Rapid Thermal Reoxidation of Si ₃ N ₄ Films in N ₂ O Ambient", IEEE Electron Device Letters, Vol. 15, No. 8, August 1994, pp. 266-268
EXAMINER <i>Michael L. Luchini</i>		DATE CONSIDERED <i>9/27/99</i>
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		